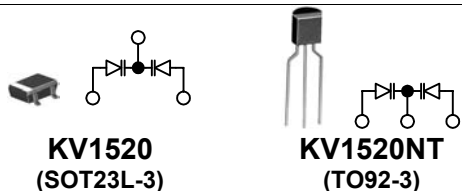


**6.5Vseries variable capacitance diode for AM tuning**  
**6.5V系AMチューナ用電圧可変容量ダイオード**



**FEATURES**

- Included twin element
- Very low operating voltage:  $V_{OP}=1.0$  to  $6.5V$
- Excellent matching between elements
- Excellent linearity of the CV curve
- High Q:  $Q=200$  to
- Extra Large Capacitance Ratio:  $A=20.0$  to
- ツインタイプ素子1組搭載
- 低電圧動作:  $V_{OP}=1.0\sim 6.5V$
- 優れた素子間マッチング
- CV特性の優れた直線性
- 高いQ値:  $Q=200\sim$
- 極めて大きな容量変化比:  $A=20\sim$

**CLASSIFICATION**

Rank		1	2	3
C <sub>1</sub>	MIN	335	353	371
	MAX	359	377	395

**ABSOLUTE MAXIMUM RATINGS**

Parameter	項目	Symbol 記号	Rating 定格	Unit 単位	Remarks 備考
Reverse Voltage	逆方向電圧	$V_R$	20	V	
Forward Current	順方向電流	$I_F$	50	mA	
Power Dissipation	許容消費電力	$P_D$	100	mW	
Storage Temperature Range	保存温度範囲	$T_{STG}$	-55 to 150	°C	
Operating Temperature Range	動作温度範囲	$T_{OP}$	-55 to +85	°C	

**ELECTRICAL CHARACTERISTICS**

$T_A=25^\circ C$

Parameter 項目	Symbol 記号	Value			Units 単位	Conditions 条件
		MIN	TYP	MAX		
Reverse Voltage 逆方向電圧	$V_R$	16			V	$I_R=10\mu A$
Reverse Current 逆方向電流	$I_R$			50	nA	$V_R=10V$
Diode Capacitance 容量値	$C_1$	335.0	360.0	395.0	pF	$V_R=1V, f=1MHz$
	$C_3$		100.0		pF	$V_R=3V, f=1MHz$
	$C_{6.5}$	14.0	15.9	17.8	pF	$V_R=6.5V, f=1MHz$
Capacitance Tolerance 容量偏差	$\Delta C_1$			1.0	%	$V_R=1V, f=1MHz^{*1}$
	$\Delta C_3$			2.0	%	$V_R=3V, f=1MHz^{*1}$
	$\Delta C_{6.5}$			2.0	%	$V_R=6.5V, f=1MHz^{*1}$
Q	Q	200				$V_R=1.2V, f=1MHz$
Capacitance Ratio 容量変化比	A	20.0				$C_1/C_{6.5}$

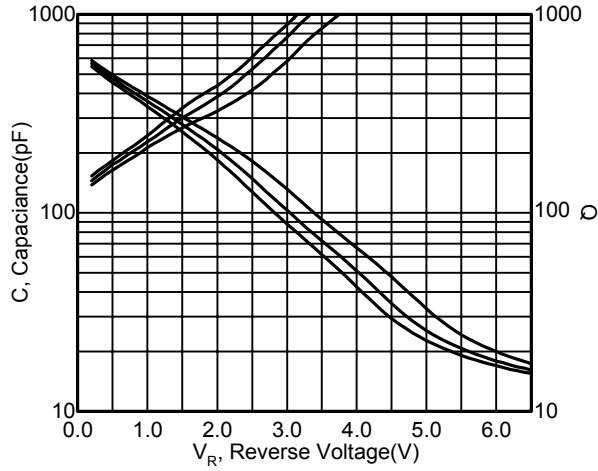
\* Diode Capacitance measured with Agilent 4279A or equivalent instruments (at OSC level  $20\pm 5mVrms$ )  
 容量測定器は、Agilent 4279A又は相当品。OSCレベル  $20\pm 5mVrms$ 。

\*1  $(C_{MAX}-C_{MIN})/C_{MIN}\times 100$

**TYPICAL CHARACTERISTICS**

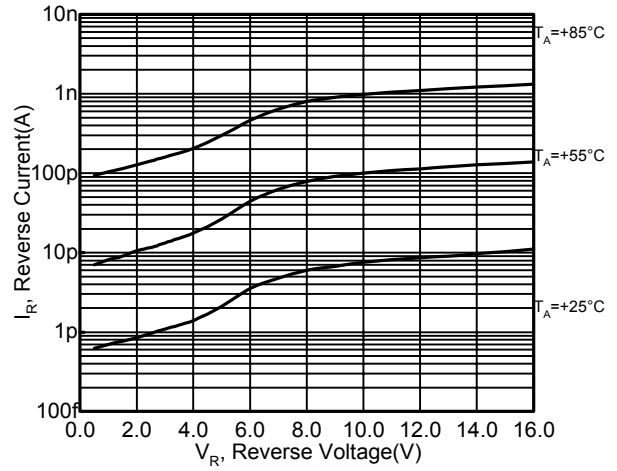
■ Capacitance, Q versus Reverse Voltage  
逆方向電圧対容量、Q

f=1MHz, T<sub>A</sub>=25°C



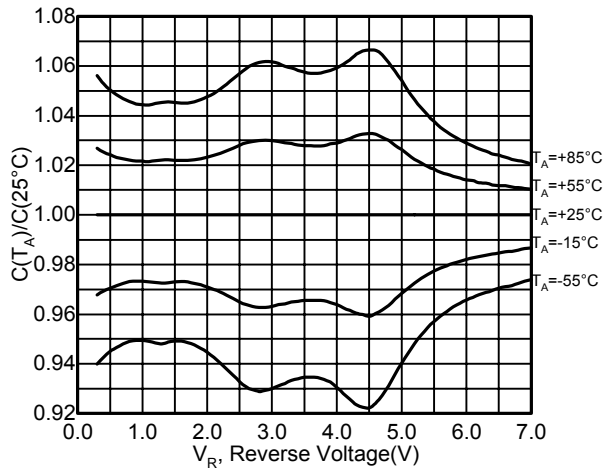
■ Reverse Current versus Reverse Voltage  
逆方向電圧対逆電流

T<sub>A</sub>=+25 / +55 / +85°C



■ C(T<sub>A</sub>)/C(25°C) versus Reverse Voltage  
逆方向電圧対C(T<sub>A</sub>)/C(25°C)

f=1MHz T<sub>A</sub>=-55 to +85°C



■ Capacitance Temperature Coefficient versus Reverse Voltage  
逆方向電圧対温度係数

f=1MHz, T<sub>A</sub>=25°C

